# 100 V, 3.0 A, Low V<sub>CE(sat)</sub> **NPN Transistor**

ON Semiconductor's e<sup>2</sup>PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

### **Features**

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Rating	Symbol	Max	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	100	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	140	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	7.0	Vdc	
Collector Current – Continuous	۱ <sub>C</sub>	2.0	Α	
Collector Current – Peak	I <sub>CM</sub>	3.0	А	

### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

### **THERMAL CHARACTERISTICS**

Characteristic	Symbol	Мах	Unit	
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 1)	490 3.7	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 1)	255	°C/W	
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 2)	710 4.3	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	176	°C/W	
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

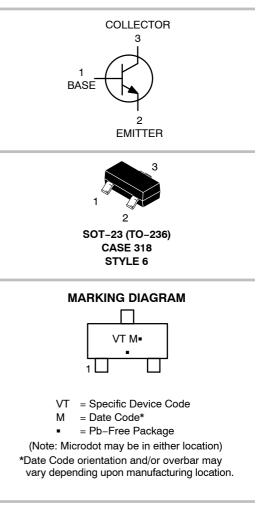
FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces.
FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces.



### **ON Semiconductor®**

http://onsemi.com

## 100 VOLTS, 3.0 AMPS NPN LOW V<sub>CE(sat)</sub> TRANSISTOR



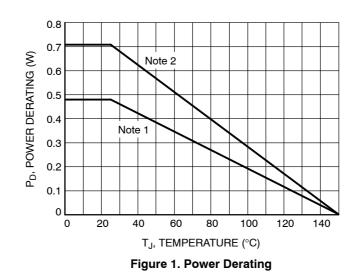
Device	Package	Shipping <sup>†</sup>
NSS1C201LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

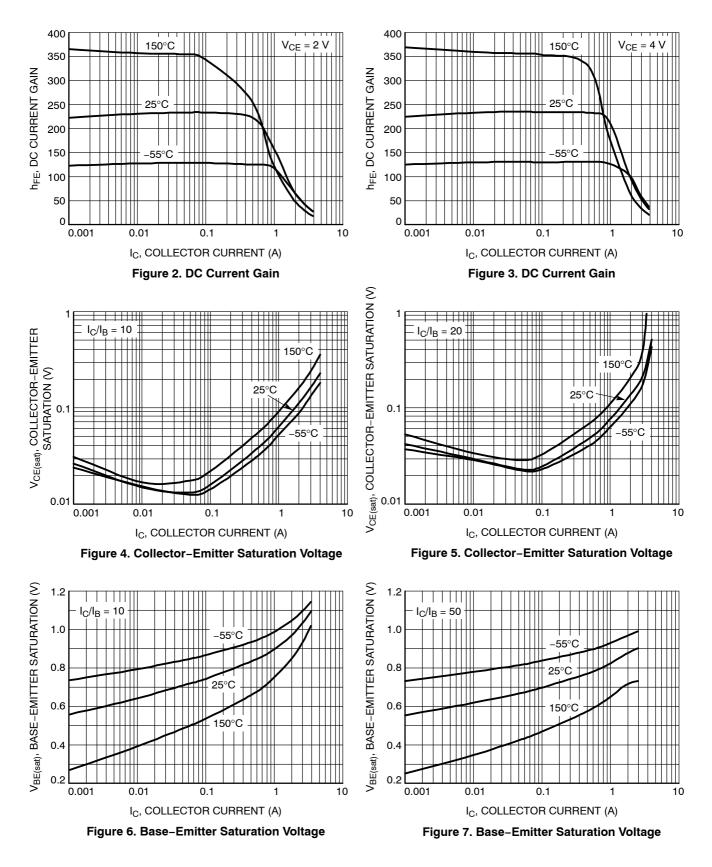
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•	
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	100			Vdc
Collector – Base Breakdown Voltage $(I_{C} = 0.1 \text{ mAdc}, I_{E} = 0)$	V <sub>(BR)CBO</sub>	140			Vdc
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	7.0			Vdc
Collector Cutoff Current (V <sub>CB</sub> = 140 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>			100	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = 6.0 Vdc)	I <sub>EBO</sub>			50	nAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3) ( $I_C = 10 \text{ mA}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	h <sub>FE</sub>	150 120 80 40	240	360	
Collector – Emitter Saturation Voltage (Note 3) ( $I_C = 0.1 \text{ A}, I_B = 0.01 \text{ A}$ ) ( $I_C = 0.5 \text{ A}, I_B = 0.05 \text{ A}$ ) ( $I_C = 1.0 \text{ A}, I_B = 0.100 \text{ A}$ ) ( $I_C = 2.0 \text{ A}, I_B = 0.200 \text{ A}$ )	V <sub>CE(sat)</sub>			0.030 0.060 0.090 0.150	V
Base – Emitter Saturation Voltage (Note 3) $(I_{\rm C} = 1.0 \text{ A}, I_{\rm B} = 0.100 \text{ A})$	V <sub>BE(sat)</sub>			0.950	V
Base – Emitter Turn–on Voltage (Note 3) ( $I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	V <sub>BE(on)</sub>			0.850	V
Cutoff Frequency ( $I_C = 100 \text{ mA}$ , $V_{CE} = 5.0 \text{ V}$ , f = 100 MHz)	f <sub>T</sub>		110		MHz
Input Capacitance (V <sub>EB</sub> = 2.0 V, f = 1.0 MHz)	Cibo		230		pF
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	Cobo		14		pF

3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq$  2%.

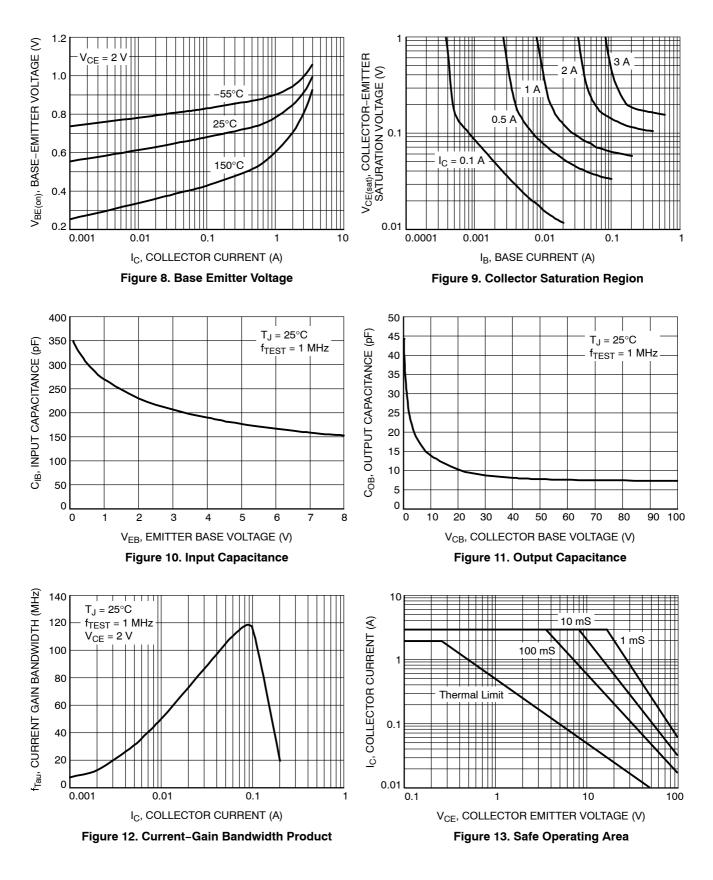


# **TYPICAL CHARACTERISTICS**

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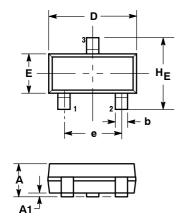


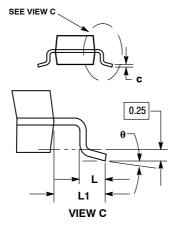
## **TYPICAL CHARACTERISTICS**



#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 





STYLE 6

PIN 1. BASE EMITTER 2

3

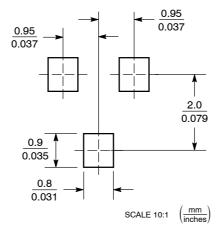
COLLECTOR

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- 2
- CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD 3. THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- 318-01 THRU -07 AND -09 OBSOLETE, NEW 4. STANDARD 318-08

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
С	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	



#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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